



# PMB134T045SS-255A

20A/45V<sup>(1)</sup>, low VF Planar MOS barrier diode

## Mechanical Data

Chip Drawing	Item	Information		
	Die Size (A)	3404μm	134.0 mil	
	Top Metal Pad Size (B)	3284μm	129.3mil	
	Chip Size (C)	/	/	
	Wafer Thickness (D)	255 μm	10.0 mil	
	Scribe Line Width (E)	80 μm	3.15 mil	
	Wafer Size	6 inch		
	Top Side Metallization	PMB134T045SS-255A	Ag	
	Back Side Metallization	Ti Ni Ag		